Tunable Energy Level Alignment in the Multilayers of Carboxylic Acids on Silver

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ABSTRACT

The precise energy level alignment between a metal electrode and an organic semiconductor is required to reduce contact resistance and enhance the efficiency of organic-semiconductor-based devices. One of the ways is to include interlayers that mediate the energy level alignment, i.e., charge injection layers (CILs). Here we introduce the monolayer thick CILs based on the aromatic carboxylic acids that can induce the energy level shift in the subsequent layers by up to 0.8 eV. By gradual chemical transformation of the as-deposited molecules, we achieve a highly tunable energy level shift in the range of 0.5 eV. We reveal that the position of both the work function and energy-level position in the CIL increases linearly with the density of induced dipoles. The energy level position of subsequent layers changes in the same way as the CIL. Our results thus connect the energy alignment quantities, i.e., energy level positions of both CIL and subsequent layers and sample work function. The high tunability would allow precise tuning of the active layers deposited on the CIL, which marks the path towards efficient charge injection layers on metal electrodes.

KEYWORDS
Charge Injection Layers, Self-Assembly; Surfaces; Photoelectron Spectroscopy; Energy Level Alignment
Organic electronics gained a significant position in the illumination and display technology\textsuperscript{1–3} with
the other areas employing organic semiconductors (OSC), i.e., organic thin-film transistors\textsuperscript{4} and
organic photovoltaics\textsuperscript{5} are on the edge of large-scale industrial applications. To utilize the OSC as
active components in fast switching electrical devices, forming good electrical contact is
essential.\textsuperscript{6–9} The interface between the OSC active layer and the metallic contacts defines the
charge injection efficiency of the device, e.g., the alignment of the molecular orbital levels of the
organic layer with vacuum and Fermi levels of the metal electrodes determines the electron- and
hole-injection, and a considerable contact resistance arises from their misalignment.\textsuperscript{7,10–12} The high
contact resistance limits the operation frequency and restricts high current devices such as organic
field-effect transistors.\textsuperscript{7,8}

One of the possibilities to reduce the contact resistance is to passivate the metal electrode by a thin
insulating layer and establish the energy level alignment (ELA) through the integer charge transfer
via the tunneling barrier.\textsuperscript{13–15} However, the tunneling contact is associated with considerable
contact resistance and energy losses despite the precise alignment.\textsuperscript{16} Hence, the direct contact of
molecules is preferable. In this case, the contact resistance can be decreased by so-called charge
injection layers (CILs) that reduce the energy level misalignment and thus increase the efficiency
of OSC-based devices.\textsuperscript{17} Both weakly and strongly interacting molecular systems were considered
for establishing a favorable ELA. In the strongly interacting systems, a partial charge transfer
between molecule and substrate provides physically robust and electronically strong
connections.\textsuperscript{18–20} On the other hand, the strong OSC–molecule–metal interaction induces
undesirable changes in surface microstructure and substantial modification of interfacial electronic
structure, which incentivizes its fine chemical tuning. The weakly interacting systems may offer flat-lying conjugated backbones available for a favorable arrangement of subsequent OSC layers, but they are also associated with significant contact resistance and prone to desorption or intermixing with molecular layers deposited above them. The heterostructures, i.e., bicomponent mixtures and bilayers of OSC, were extensively studied to address these issues. However, these studies mainly described their complex structure and electronic properties. Only a few studies provided hints on ELA in subsequent layers, and the lack of fundamental understanding makes the design of the optimal CILs challenging. To address these issues, we employ 4,4′-biphenyl dicarboxylic acid (BDA, Figure 1a) to prepare a range of single-layer molecular CILs with a tunable density of interface dipoles; these dipoles induce energy level shifts of subsequently deposited molecular layers by up to 0.8 eV.

The employed molecular system does not have a counterpart in the bulk phase. The molecules in direct contact with metal substrate chemically transform when annealed to elevated temperatures – their carboxyl groups deprotonate (Figure 1b). Hence, we obtain three chemically distinct molecular species with similar structures. After removing hydrogen, the resulting carboxylate group possesses a partial negative charge, and an interfacial dipole is formed. By gradual deprotonation, we can prepare a range of molecular phases with a distinct density of dipoles \( n_{\text{Dip}} \). For each molecular phase the \( n_{\text{Dip}} \) is obtained as \( n_{\text{Dip}} = 2Dn_{\text{BDA}} \), where \( D \) is degree of deprotonation in particular phase and \( n_{\text{BDA}} \) is surface density of BDA molecules in this phase each having 2 carboxyl groups. On Ag(001) surface, four distinct stable phases were considered as CILs: \( \alpha, \dot{\alpha}, \beta, \) and \( \delta \), with \( n_{\text{Dip}} \) ranging from 0 (\( \alpha \)), via 1.17 (\( \beta \)), 1.25 (\( \dot{\alpha} \)) to 2.28 dipoles per nm\(^2\) (\( \delta \)). On Ag(111) surface, we have considered \( \alpha \) and \( \beta \) phases (0 and 1.22 dipoles per nm\(^2\), respectively). In the following, we will designate the full monolayers of these phases as CILs and
denote them by with the Greek letter standing for the molecular phase with the orientation of the surface plane in the index, e.g., $\beta_{(001)}$ stands for the $\beta$ phase on Ag(001) surface. The morphological structure of all CILs is given in \textbf{Figure 1c}.

\textbf{Figure 1}: Molecule and CILs employed in this study. (a) Chemical structure of 4,4'-biphenyl dicarboxylic acid (BDA). (b) Partially- and fully-deprotonated BDA have a similar structure but largely differing properties compared to intact BDA. (c) STM images of distinct CILs considered in this study.

Both the CIL and subsequent layers were deposited under ultra-high vacuum UHV conditions (base pressure below $2 \times 10^{-10}$ mbar) on surfaces of Ag(001) and Ag(111) single crystals cleaned by repeated cycles of Ar$^+$ sputtering and annealing at 520 °C. All analyses were performed under UHV conditions without exposing the sample to the ambient. We have employed synchrotron radiation photoelectron spectroscopy\textsuperscript{36} as the primary tool to determine the electronic properties
of CILs; the measurements were performed at the Materials Science Beamline at Elettra synchrotron light source in Trieste. We used 40.8, 420, 510, and 670 eV excitation energies to measure the valence band, C 1s, Ag 3d$_{5/2}$, and O 1s spectra, respectively. The experimental details are the same as reported previously. The synchrotron measurements were combined with laboratory measurements in which we developed the methodologies to prepare CILs by UHV deposition and subsequent thermal annealing. We have employed low-energy electron microscopy (LEEM) to assess the coverage, low-energy electron diffraction (LEED), and scanning tunneling microscopy (STM) to determine the structure, and X-ray photoelectron spectroscopy (XPS) to measure the chemical composition and electronic properties of the samples; the experimental parameters were detailed previously.

Figures 2a–d show the photoelectron spectra of the 2$^{nd}$ BDA layer deposited on $\alpha_{(001)}$ and $\tilde{\alpha}_{(001)}$ CILs. The spectra measured before the 2$^{nd}$ layer deposition were used as a reference; they are provided in Supporting Information, Sections 1 and 2, together with spectra of all other CILs. The O 1s spectra of the $\alpha_{(001)}$ CIL in Figure 2c shows two peaks associated with hydroxyl (at 534.05 eV binding energy, BE) and carbonyl (532.65 eV) oxygens of carboxyl groups. Upon thermal annealing of $\alpha_{(001)}$ CIL to 70 °C, half of the carboxyl groups deprotonate and the $\tilde{\alpha}_{(001)}$ CIL is formed. The O 1s spectrum significantly changes: there is one dominant component at 530.9 eV associated with carboxylate oxygen and two peaks at 532.8 and 531.45 of the two oxygen atoms of the carboxyl group bound to carboxylate (red-colored peaks in Figure 2d). After the deposition of the 2$^{nd}$ layer of BDA, two new components appeared in the photoelectron spectrum (Figure 2c); their BEs of 534.2 and 532.8 and 1:1 ratio of intensities is close to the as-deposited BDA multilayers. The peaks with the same separation and intensity ratio also appear in spectra of
the 2\textsuperscript{nd} BDA layer on top of $\alpha_{(001)}$ CIL (Figure 2d) but shifted to lower BEs (533.7 and 532.30 eV). The presence of well-defined peaks associated with protonated carboxyl groups suggests that the 2\textsuperscript{nd} layer BDA molecules are intact, i.e., non-deprotonated. The intact BDA molecules in the 2\textsuperscript{nd} layer were also found for all other CILs in this study. No deprotonation in the 2\textsuperscript{nd} layer was observed even on $\delta_{(001)}$ CIL, which features only deprotonated BDA molecules, even after annealing at elevated temperatures. The 2\textsuperscript{nd} BDA layer started to desorb at 75 °C and disappeared at 100 °C. Up to the desorption temperature, no changes in the peaks except for the reduction in their intensity were observed.

The C 1s spectrum of $\alpha_{(001)}$ CIL (Figure 2a) shows the main component at 285.25 eV; it can be associated with the C atoms of phenyl rings. The carboxylic C 1s component is shifted by 4.4 eV to higher BE; the remaining features are associated with the extensive shake-up satellite structure.\textsuperscript{37,38} After deposition of the BDA overlayer, the main peak significantly broadens. Taking the CIL spectra as a reference, a new component related to 2\textsuperscript{nd} layer C in phenyl rings becomes apparent in Figure 2a. It has the same width and comparable intensity as the CIL peak, but shifted by 0.35 eV to higher BE. For the $\alpha_{(001)}$ CIL the spectrum in Figure 2b is similar, but both CIL and 2\textsuperscript{nd} layer peaks are shifted to lower BEs compared to $\alpha_{(001)}$ CIL: the CIL peak is at 284.65 eV, and the 2\textsuperscript{nd} layer peak at 0.35 eV higher BEs related to CIL. Remarkably for both the $\alpha_{(001)}$ and $\delta_{(001)}$ CILs the shift of the 2\textsuperscript{nd} layer peak relatively to the CIL one is the same.
Figure 2: Photoelectron spectroscopy analysis of the 2nd layer of BDA on CILs. (a, b) C 1s spectra measured by synchrotron radiation with an energy of 420 eV from samples comprising 0.7 ML of BDA deposited on α(001) and α(001) CILs. The peak components are marked accordingly; the full description and peak parameters for all CILs are given in Supporting Information. (c, d) O 1s spectra (670 eV) of 0.7 ML of BDA deposited on α(001) and α(001) CILs. The vertical lines mark
the shift of peaks discussed in the text. (e, f, g) Position of the 2nd layer peaks as a function of the CIL O 1s position (e), CIL phenyl C 1s position (f), and 2nd layer O 1s position (g). The gray point for δ(001) marks an incompletely formed layer. The energy scale is the same on both axes in each panel. The blue value denotes the slope of the linear fit (black line).

Figures 2e and f compare the energy shifts of carbonyl O 1s and C 1s peaks in the 2nd layer and the CIL. The O 1s peak components shift differently in the CIL and the 2nd layer (Figure 2e). This indicates a strong interaction of carboxylate oxygens with the substrate,22 which is accompanied by significant electronic transfer as shown by our DFT calculations given in Supporting Information, Section 3. In contrast, the C 1s peak component associated with phenyl rings shows a comparable shift in both CIL and the 2nd layer (Figure 2f; the slope is close to 1). The rigid shift hints at the absence of chemical interaction of C species with the substrate. Finally, Figure 2g shows that the O 1s and C 1s peaks in the 2nd BDA layer exhibit the same BE shift; this implies no chemical interaction of the 2nd layer molecules with all CILs. The position of the energy levels of the 2nd layer BDA in the valence band region follows a similar trend: their shift is consistent with the shift of core levels as shown in Supporting Information, Section 4. The same shift of core and valence band levels occurs when molecular levels are pinned to the vacuum level.22,39 Hence, we can employ the core levels shifts to assess the changes in frontier molecular orbitals. We note that with an increasing overlayer thickness, the overlayer peaks shift towards the bulk values as given in Supporting Information, Section 5; this behavior is typical for OSCs on metal electrodes.10,21,40

The observed shifts in the 2nd layer energy levels in the range of 0.8 eV indicate that the considered BDA molecular phases can act as CILs. The BDA C 1s core level positions are summarized for all
CILs in Supporting Information, Section 6. These positions are supplemented by work functions (WF) determined for the CILs from measured secondary electron cutoff energies and positions of the respective Fermi levels,\textsuperscript{10,40,41} as detailed in Supporting Information, Section 7. During the thermal treatment of sub-monolayer BDA, we have established that the work function increases linearly with the degree of deprotonation of BDA’s carboxyl groups as detailed in Supporting Information, Section 8. The linear dependence can also be established between the position of the CIL C 1s peak and the measured WF of the full molecular layer, as given in Figure 3. Two effects contribute to the total change of the work function $e\Delta \varphi$, i.e., the formation of molecular dipoles $e\Delta \varphi_{\text{Dip}}$ and the adsorbate-induced change in surface potential $e\Delta V_s$:\textsuperscript{42}

$$e\Delta \varphi = e\Delta \varphi_{\text{Dip}} + e\Delta V_s.$$  

The first term comprises contributions from the interface and intramolecular dipoles and from the pushback effect. The second term is associated with band bending; it equals zero at the surface of the metal. Deposited molecules induce the pushback effect that decreases the work function.\textsuperscript{10,22,43,44} The deprotonated carboxyl groups display a negative charge localized on the O atoms,\textsuperscript{33,45} which results in the formation of interface and intramolecular dipoles that increase the WF.\textsuperscript{46–49} Consistently with our DFT calculations summarized in Supporting Information, Section 3, the $\alpha_{(001)}$ CIL displays a work function 0.61 eV lower than Ag(001) substrate, the $\alpha_{(001)}$ CIL work function is similar to the substrate (0.02 eV higher), and the $\delta_{(001)}$ CIL has a WF 0.28 eV higher than the bare Ag(001) substrate. DFT calculations reveal that the formation of interface and intramolecular dipoles are the main contributions to the WF change $\Delta \varphi$ during the deprotonation. In line with the WF change, the molecular energy levels shift accordingly. This is consistent with the studies on OSC bilayers in which the local electrostatic potential of formed interface dipoles was identified as the origin of the change in molecular orbital energies.\textsuperscript{29,30}
Figure 3: Dependence of work function on the position of C 1s component associated with phenyl rings for BDA CILs marked at each point. The inset shows a schematic diagram with energy level positions for limiting CILs ($\alpha_{(001)}$ and $\delta_{(001)}$): vacuum level $E_V$, Fermi level $E_F$, C 1s core level position of BDA in CIL and the 2nd layer, and work function shifts $\Delta \varphi$ induced by CILs. Blue lines present the measured work functions with respect to the bare substrate. The red and green lines mark the positions of the C 1s peak of BDA in CILs and 2nd layers, respectively.

Finally, we present a continuous tuning of 2nd layer energy level position, which is enabled by increasing the dipole density $n_{\text{Dip}}$ during the continuous isostructural phase transformation of the $\alpha_{(001)}$ to the $\delta_{(001)}$ CIL. This transition can be achieved by sample annealing at 70 °C or by secondary electrons during exposure by X-ray radiation. As the 2nd layer BDA already desorbs at 70 °C, the second option is favorable and enables simultaneous XPS analysis. X-ray irradiation-induced deprotonation is restricted to the molecular layer that is in immediate contact with the Ag
surface. Hence, in the case of 2 ML of BDA, only BDA molecules in the first layer will slowly deprotonate ($D \sim 0.5$ was reached in 42 hours of irradiation) and the $n_{\text{Dip}}$ will continuously increase. Snapshots from the series of simultaneously measured XPS spectra and their processing are presented in Supporting Information, Section 9. Figure 4 shows the shift of the 2nd layer O 1s peak as a function of density of interface dipoles that change from 0 to 1.25 nm$^2$. The graph of O 1s position as function of $D$ is given in Figure S12. The 2nd layer energy level position upshifts linearly by 0.4 eV for $n_{\text{Dip}}$ up to 0.6 nm$^2$ ($D = 0.25$), beyond which it slows down: an additional shift by 0.1 eV is obtained for $n_{\text{Dip}} = 1.25$ nm$^2$ ($D = 0.5$).

As discussed earlier, the upshift of electronic levels in the 2nd layer is caused by the dipole component of the work function change $e\Delta \varphi_{\text{Dip}}$. In line with previous works on weakly-interacting molecules that carry electric dipole, the dependence of $e\Delta \varphi_{\text{Dip}}$ on $n_{\text{Dip}}$ can be expressed as

$$e\Delta \varphi_{\text{Dip}} = \frac{e}{\varepsilon_0} \mu n_{\text{Dip}} \left(1 + \frac{9\alpha}{4\pi\varepsilon_0 n_{\text{Dip}}^{3/2}}\right)^{-1}, \quad (1)$$

where $\mu$ is the dipole moment, $\alpha$ the polarizability of a surface-molecule complex, and $\varepsilon_0$ the permittivity of the vacuum. The modeling of the measured data is given in Figure 4. The fit of the low dipole density part, in which it is sufficient to take only the linear part of (1), i.e., $\frac{e}{\varepsilon_0} \mu n_{\text{Dip}}$, gives the value of the electric dipole moment $\mu = (1.4 \pm 0.2)$ D. Employing the value for the full model gives the polarizability volume $\frac{\alpha}{4\pi\varepsilon_0} = (3 \pm 1) \cdot 10^{-29}$ m$^3$; both values are consistent with those of similar systems. Our DFT calculations (Supporting Information, Section 3) give a value of dipole moment change of 1.2 D in good agreement with the experimental value. Applying the model and derived values for $\delta_{(001)}$ gives an energy shift of $(0.64 \pm 0.08)$ eV consistent with the measured value of 0.71 eV. The applicability of the model in eq. (1) for the energy level shifts...
in the 2\textsuperscript{nd} layer of deposited molecules shows that the change in the energy level position is caused by the dipolar contribution of the work function change.

**Figure 4**: The shift of the 2\textsuperscript{nd} layer O 1s peak as a function of electric dipole density $n_{\text{Dip}}$ during the isostructural $\alpha_{(001)}$ to $\alpha_{(001)}$ transformation. The red line is a linear fit of the initial region, and the blue curve is the full model given by Eq. (1). The initial, intermediate, and final spectra and fitting procedure are given in Supporting Information, Section 9.

In conclusion, we have employed a single molecule to prepare a range of CILs on Ag(001) and Ag(111) surfaces by controlled deprotonation of the carboxylic groups, which results in the formation of interface dipoles with densities up to 2.3 nm\textsuperscript{-2}. These dipoles induce a shift in electronic levels of molecular overlayers by up to 0.8 eV. We found a linear relation with a slope close to 1 between the shift of BDA electronic levels and the dipolar contribution of the electrode work function change. The presented CILs feature flat-lying phenyl rings electronically strongly coupled to the metal substrate. The phenyl rings could serve as the favorable template for the
growth of OSCs in the bulk-like structure. The possibility of a continuous shift of energy levels of molecular overlayers in the range of 0 to 0.4 eV makes the presented system a prospective candidate for the realization of efficient CILs in electronic devices featuring OSC.
SUPPLEMENTARY MATERIAL

See supplementary material for: (1) Analysis of the photoelectron spectra of BDA CILs on Ag(001); (2) Analysis of the photoelectron spectra of BDA CILs on Ag(111); (3) DFT calculations of dipole moment in the $\alpha_{(001)}$ phase; (4) Mutual position of valence and O 1s peaks in the 2nd layer; (5) Position of the overlayer peaks as a function of the overlayer thickness; (6) Summary of energy level positions determined for studied CILs; (7) Work function measurement of CILs on Ag(001) and Ag(111) substrates; (8) Change of work function during the thermal-induced transformation;; and (9) Details of fitting of the XPS data: gradual deprotonation of the first layer.

AUTHOR’S INFORMATION

**Author’s Contributions**

P.P. provided the initial idea. P.P. and J.Č. conceptualized the research. V.S. prepared the samples and performed all laboratory investigations. V.S., P.P. A.M., T.S., M.B., and J.Č. performed the synchrotron radiation experiments. J.P. and A.S. did DFT calculations. J.Č. developed the methodology, supervised the experiments, analyzed and interpreted the data, and wrote the manuscript.

**Competing interests**

The authors declare no competing financial interests.
ACKNOWLEDGMENTS

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DATA AVAILABILITY

The data that support the findings of this study are available from the corresponding author upon reasonable request.
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SUPPORTING INFORMATION

Tunable Energy Level Alignment in the Multilayers of Carboxylic Acids on Silver

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10. References
1. Analysis of the photoelectron spectra of BDA CILs on Ag(001)

The O 1s spectra were fitted by 2 – 3 Voigt components (parameters given in Table S1) using a Shirley background, as shown in Figure S1. All fits are consistent with our previous laboratory measurements using a standard, non-monochromatic X-ray source.\textsuperscript{1,2} For the bilayers (Figure S1b), we have introduced two additional peaks representing the α phase in the 2\textsuperscript{nd} BDA layer. For the CIL, we have used the previously obtained peak positions, Gaussian widths, and intensity ratios and allowed change only in the peak intensity.

The spectra of the α\textsubscript{(001)} CIL reveal slight initial deprotonation (the degree of deprotonation is 0.1). For the δ\textsubscript{(001)} CIL, the spectra show a residual degree of deprotonation of 0.80 or 0.95. This is a balance between keeping the high BDA coverage while reaching a high degree of deprotonation. There is a very narrow interval of temperatures for the phase transformation, where the coverage is maintained, and significant BDA deprotonation occurs. Partial desorption is probably the reason for a lower coverage of 0.95; the particular point is highlighted in a lighter shade of gray in Figure 2 of the main text.

Concerning the C 1s spectra (Figure S2), the synchrotron radiation provides a much higher resolution than achievable in our laboratory. This enabled us to distinguish components of the phenyl-ring-associated components (C1 component), split of carboxyl related C 1s component (C2 component) in the α\textsubscript{(001)} and δ\textsubscript{(001)} CILs, and better visualize the presence of shake-up satellites. Nevertheless, the peak-fitting parameters (Table S2) are similar to those obtained by a non-monochromatic X-ray source. The bilayer sample was fitted with parameters of the previously measured CILs fixed except for their intensity.

The presence of the extensive shake-up satellite structure\textsuperscript{3,4} complicates the precise fitting of carboxyl-related components, as discussed previously for BDA on Ag(111) substrate.\textsuperscript{5} Therefore, we did not consider the position of carboxyl-group-related components (C2) to discuss CIL properties.

The spectra for the valence band region (0 – 14 eV) are shown in Figure S3. The analysis is complicated by a significant overlap of BDA-related peaks with the Ag ones. Hence, we have taken the deepest one (9.3 – 10.3 eV) for further investigation.
Table S1: Peak-fit parameters: binding energy position (BE) and FWHM of the Gaussian part of the O 1s peak components. Voigt function was used for fitting; the width of the Lorentzian component was 0.1 eV. The BE shifts (from the peak, marked +0.0) are given in brackets. The degree of deprotonation of carboxyl groups is provided for all the phases.

<table>
<thead>
<tr>
<th>Component O1 (hydroxyl oxygen)</th>
<th>Component O2 (carbonyl oxygen)</th>
<th>Component O3 (carboxylate oxygen)</th>
<th>Degree of Deprotonation</th>
</tr>
</thead>
<tbody>
<tr>
<td>CIL Ag(001)</td>
<td>BE (eV)</td>
<td>FWHM (eV)</td>
<td>BE (eV)</td>
</tr>
<tr>
<td>α</td>
<td>534.05 (+1.4)</td>
<td>1.4</td>
<td>532.65 (+0.0)</td>
</tr>
<tr>
<td>α</td>
<td>532.80 (+1.35)</td>
<td>1.4</td>
<td>531.45 (+0.0)</td>
</tr>
<tr>
<td>β</td>
<td>532.80 (+1.35)</td>
<td>1.4</td>
<td>531.45 (+0.0)</td>
</tr>
<tr>
<td>δ</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

The position of the Ag 3d5/2 peak was in the interval of (368.20 ± 0.02) eV for all the measurements, which confirms that the energy tuning reproducibility is much better than the spectral resolution.

Table S2: Peak-fit parameters: binding energy position (BE) and FWHM of the Gaussian part of the C 1s peak components. Voigt function was used for fitting; the width of the Lorentzian component was 0.2 eV. The BE shifts (from the peak, marked +0.0) are given in brackets. The ratio of the C2 and C1 intensities match the theoretical one (2/12 = 0.167). A shoulder for the C1 component was necessary to obtain a good fit for CIL; it was shifted by 0.7 eV to higher binding energy, its intensity was 0.165 of the main component, and it had the same Gaussian width. It models the weak asymmetry of the main peak, and since its parameters are constrained, it does not represent any additional degree of fitting freedom.

<table>
<thead>
<tr>
<th>Component C1 (phenyl rings)</th>
<th>Component C2 (carboxyl carbon)</th>
<th>C2/C1</th>
</tr>
</thead>
<tbody>
<tr>
<td>CIL Ag(001)</td>
<td>BE (eV)</td>
<td>FWHM (eV)</td>
</tr>
<tr>
<td>α</td>
<td>285.25 (+0.0)</td>
<td>1.0</td>
</tr>
<tr>
<td>α</td>
<td>284.65 (+0.0)</td>
<td>0.8</td>
</tr>
<tr>
<td>β</td>
<td>284.65 (+0.0)</td>
<td>0.8</td>
</tr>
<tr>
<td>δ</td>
<td>284.50 (+0.0)</td>
<td>0.8</td>
</tr>
</tbody>
</table>

The position of the Ag 3d5/2 peak was in the interval of (368.20 ± 0.02) eV for all the measurements, which confirms that the energy tuning reproducibility is much better than the spectral resolution.
Figure S1: O 1s spectra of (a) CILs on Ag(001) surface and (b) 0.7 ML of BDA on the CILs on Ag(001). The vertical lines mark the peak positions used to describe CIL properties.
Figure S2: C 1s spectra of (a) CILs on Ag(001) surface and (b) 0.7 ML of BDA deposited on the CILs. The vertical lines mark the peak positions used to describe CIL properties.
Figure S3: Valence band spectra of Ag(001) surface (black), CILs (red), and 0.7 ML of BDA on the CILs (blue). The spectrum of 8 ML of BDA (green) is given for reference of BDA energy levels (thick BDA layer on the δ(001) CIL).
2. Analysis of the photoelectron spectra of BDA CILs on Ag(111)

The fitting of spectra associated with the BDA layers on both $\alpha$ and $\beta$ phase CILs is given in Figure S4; we have employed the previously reported C 1s and O 1s peak parameters. The measured valence band spectra are given in Figure S5.

![Figure S4](image)

**Figure S4**: C 1s (a) and O 1s (b) spectra of BDA deposited on CILs on Ag(111) surface. The vertical lines mark the peak positions used to describe CIL properties.
Figure S5: Valence band spectra of Ag(111) surface (black), CILs (red), and BDA on the CILs (blue). The spectrum of 8 ML of BDA (green) is given to provide a reference of BDA energy levels (thick BDA layer on $\beta_{(111)}$ CIL).
3. DFT calculations of dipole moment in the $\alpha_{(001)}$, $\tilde{\alpha}_{(001)}$ and $\delta_{(001)}$ phases

All calculations were performed with the Vienna ab initio Simulation Package (VASP). The projector-augmented wave (PAW) method was employed for treating core electrons. For silver, oxygen, hydrogen, and carbon 11 valence electrons ($5s^14d^{10}$), 6 valence electrons ($2s^22p^4$), 1 valence electron ($1s^1$) and 4 valence electrons ($2s^22p^2$), respectively, were expanded in a plane-wave basis set with an energy cut-off set to 450 eV. The Brillouin zone was sampled with a Γ-centered Monkhorst-Pack grid, using more than 17 $k$-points per Å$^{-1}$ for all structural relaxations and 60 $k$-points per Å$^{-1}$ for subsequent electronic structure calculations. Ionic relaxations were stopped when all residual forces became smaller than $4\times10^{-2}$ eV/Å. In all calculations, total energy, potential, and forces were corrected for finite-size errors. All slabs consisted of eight layers with lateral cell dimensions corresponding to the optimized silver bulk lattice constants. For $\alpha_{(001)}$, $\tilde{\alpha}_{(001)}$ and $\delta_{(001)}$ phases the BDA molecular layers were adapted to the silver (001) supercell with the matrix notations $\begin{pmatrix} 3 & 2 \\ -2 & 2 \end{pmatrix}$ for the first two listed and $\begin{pmatrix} 3 & 5 \\ -3 & 2 \end{pmatrix}$ for the last one. All structures are depicted in Figure S6a, b, c. All slabs were separated by a vacuum gap of 18 Å. We used non-local optB88-vdW DFT functional to describe the exchange-correlation energy. Benchmark calculations using PBE-D$^3$ and optB86b-vdW$^2$ functionals showed no qualitative differences in the evaluated dipole moments.

The dipole moment for each phase was calculated as the sum of interface ($\mu_{\text{int}}$) and intramolecular ($\mu_{\text{mol}}$) dipole moments. The interface dipole moments contain a contribution from the push-back effect and a contribution from the interface dipoles induced by the charge transfer. The latter term contains a dipole moment localized within the molecular layer. It is induced by bending of BDA molecules (see Figure S6g, h, i) due to strong interaction of deprotonated carboxylic groups with the silver substrate. Absolute values of interface dipole moments were calculated from the electron density difference ($\Delta \rho$) between the silver substrate and the molecular layer, defined as:

$$\Delta \rho = \rho_{\text{BDA+Ag}} - \left( \rho_{\text{BDA}} + \rho_{\text{Ag}} \right). \quad (S1)$$

where $\rho_{\text{BDA+Ag}}$ is the total electronic density of the combined system, $\rho_{\text{Ag}}$ marks the electron density of the silver substrate without the molecular layer, and $\rho_{\text{BDA}}$ is the electron density of free-standing BDA monolayer. The expression for interface dipole moments reads:

$$\mu_{\text{int}} = \iiint z \cdot \Delta \rho(x, y, z) \, dx \, dy \, dz. \quad (S2)$$
In this case, we set the origin of $z$ axis to the center of gravity, i.e.:

$$z(0) = -\frac{\int \int \rho(x,y,z) dxdydz}{\int \int \Delta \rho(x,y,z) dxdydz}, \quad (S3)$$

which was calculated to be \(\sim 0.98 \text{ Å}, \sim 0.75 \text{ Å} \) and \(\sim 0.99 \text{ Å} \) above the silver surface layer for $\alpha_{(001)}$, $\hat{\alpha}_{(001)}$ and $\delta_{(001)}$ phases, respectively; see Figure S6d, e, f. The intramolecular part of the dipole moment was calculated from the total charge density of the molecular layer, including the ionic contribution:

$$\mu_{\text{mol}} = \int \int \int z \cdot \rho_{\text{BDA}} dxdydz - \sum_{i}^{N} Z_{i} \cdot q_{i}, \quad (S4)$$

where $N$, $Z_{i}$ and $q_{i}$ denote the number of ions in the molecular layer, their positions, and charges, respectively. The resulting dipole moment, i.e., $\mu_{\text{tot}} = \mu_{\text{int}} + \mu_{\text{mol}}$ is in perfect agreement (less than 0.06 D in absolute values) with its evaluation from a work function change.$^{13}$ Calculated interface, intramolecular and total dipole moments for $\alpha$, $\hat{\alpha}$ and $\delta$ phases are listed in Table S3.

Charge transfer between the substrate and molecular layer can be defined as the maximum absolute value of the cumulative charge transfer function $Q(z).^{14}$ This function represents the total charge transferred below a plane at position $z$:

$$Q(z) = \int \int \int_{-\infty}^{z} \Delta \rho(x,y,z) dxdydz. \quad (S5)$$

Optimized structures, averaged electron density differences after adsorption and electronic charge transfer functions for $\alpha_{(001)}$, $\hat{\alpha}_{(001)}$ and $\delta_{(001)}$ phases are depicted in Figure S6. As shown in Figure S6d, \(~0.1 \) electrons from the $\alpha_{(001)}$ phase are transferred to the silver substrate, which induces the interface dipole moment of $\mu_{\text{int}} = -1.16 \text{ D}$ while the molecule stays planar and we observe only a small contribution from intramolecular dipole moment, $\mu_{\text{mol}} = -0.05 \text{ D}$. After deprotonation of the $\alpha_{(001)}$ phase, i.e., removal of the hydrogen atom marked in Figure S6a and transformation to $\hat{\alpha}_{(001)}$ (Figure S6b), the molecular system undergoes qualitative changes both in the structure and in the electronic configuration. The deprotonated carboxylic group is pushed towards the silver substrate, which causes bending of BDA molecules (Figure S6g, h). This is accompanied by two effects: First, \(~0.2 \text{ e}^{-} \) are transferred from the silver substrate to the molecular layer (Figure S6e), which increases the interface dipole moment to $\mu_{\text{int}} = 0.98 \text{ D}$. Second, the intramolecular dipole moment is decreased to $\mu_{\text{mol}} = -1.01 \text{ D}$ due to the out-of-plane deviation of negatively charged
oxygen atoms, see Table S3. Hence, the total dipole moment in the $\alpha_{(001)}$ phase is increased by 1.17 D with respect to $\alpha_{(001)}$ phase. After full deprotonation of the $\alpha_{(001)}$ phase and transformation

Figure S6: (a–c) Calculated unit cells for $\alpha$, $\dot{\alpha}$ and $\delta$ phases. Cyan, black, red and white spheres represent Ag, C, O and H atoms, respectively. The orange circle marks an extra hydrogen atom in the $\alpha$ phase. (d-f) Averaged electron density difference over the $xy$ plane and charge transfer functions for $\alpha$, $\dot{\alpha}$ and $\delta$ phases, respectively. The black horizontal line represents the calculated center of a dipole (see eq. S3). (g–i) Charge density redistribution in the $\alpha$, $\dot{\alpha}$, and $\delta$ phases induced by an interaction between a silver substrate and a molecular layer. The red arrow marks the shift of a deprotonated carboxylic group towards a silver substrate.
to the $\delta_{(001)}$ phase (Figure S6c), both contributions to the resulting dipole moment and charge transfer functions follow the same trend. First, charge transfer from the silver substrate increases to $\sim$0.5 e$^-$ (Figure S6f) which also increases the interface dipole moment to $\mu_{\text{int}} = 2.98$ D. Second, the BDA molecules undergo even more prominent bending (Figure S6i), which is accompanied by an additional decrease of intramolecular dipole moment to $\mu_{\text{mol}} = -2.20$ D. As a result, the total dipole moment is increased by 0.82 D with respect to $\alpha_{(001)}$ phase. This change is 30% smaller with respect to transformation of $\alpha_{(001)}$ to $\alpha_{(001)}$ due to smaller increase of interface dipole moment by 0.14 D and larger decrease of intramolecular dipole moment by 0.23 D. This is consistent with work function measurements as a function of deprotonation level, showing milder slope after transformation to $\beta_{(001)}$ phase (Figure S11). Finally, resulting changes of the calculated work function (Table S3) are in perfect agreement with experiment (Figure S9): they differ by 0.08 eV, 0.06 eV and 0.05 eV for $\alpha_{(001)}$, $\alpha_{(001)}$ and $\delta_{(001)}$ phases, respectively.

**Table S3:** Calculated dipole moments and work function changes for $\alpha_{(001)}$, $\alpha_{(001)}$ and $\delta_{(001)}$ phases. Calculated dipole moments for the $\delta_{(001)}$ phase are normalized to the size of the $\alpha_{(001)}$ supercell.

<table>
<thead>
<tr>
<th>phase</th>
<th>$\mu_{\text{int}}$ [D]</th>
<th>$\mu_{\text{mol}}$ [D]</th>
<th>$\mu_{\text{tot}}$ [D]</th>
<th>$e\Delta \varphi$ [eV]</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\alpha_{(001)}$</td>
<td>-1.16</td>
<td>-0.05</td>
<td>-1.20</td>
<td>-0.53</td>
</tr>
<tr>
<td>$\alpha_{(001)}$</td>
<td>0.98</td>
<td>-1.01</td>
<td>-0.03</td>
<td>-0.04</td>
</tr>
<tr>
<td>$\delta_{(001)}$</td>
<td>2.98</td>
<td>-2.20</td>
<td>0.79</td>
<td>0.33</td>
</tr>
</tbody>
</table>
4. Mutual position of valence and O 1s peaks in the 2\textsuperscript{nd} layer

Figure S7 shows that core-level binding energy shift is comparable to the frontier orbitals (HOMO) shift in the valence band region. Hence, the core levels can describe the energy level alignment between BDA and Ag surfaces.

**Figure S7**: Position of 2\textsuperscript{nd} layer peak associated with one of the highest lying occupied molecular orbitals (marked by a blue vertical line in Figures S3 and S5) on the position 2\textsuperscript{nd} layer O2 component (Figures S2b and S4b) for all considered BDA CILs.
5. Position of the overlayer peaks as a function of the overlayer thickness

The evolution of the overlayer O 1s and C 1s peak positions with increasing BDA layer thickness is presented in Figure S8 for all considered CILs.

**Figure S8**: Position of (a) 2nd layer O 1s peak (O2 component, marked with a vertical line in Figure S2b) and (b) 2nd layer C 1s peak (C1 component, marked with a vertical line in Figure S1b) as a function of overlayer (i.e., 2nd layer and above) thicknesses deposited on BDA CILs.
6. Summary of energy level positions determined for studied CILs

Figure S9: Summary of energy level positions determined for studied CILs: vacuum level $E_V$, Fermi level $E_F$, C 1s core level position of BDA in CIL and the 2nd layer and work function shifts $\Delta \phi$ induced by CILs. Blue lines present the measured work functions in respect to the bare substrate (mean literature values\textsuperscript{15} are given). The red and green lines mark the positions of the C 1s peak of BDA in CILs (red lines) and 2nd layers (green lines).
7. Work function measurement of CILs on Ag(001) and Ag(111) substrates

We have determined the work function for all considered CILs and bare substrates employing a standard procedure of measuring secondary electron cut-off (SEC) and Fermi levels. To enable the measurement of the SEC, we have applied a 7 V bias to the sample. Subsequently, we have shifted the spectra back according to the measured Fermi level position, setting it to 0.00 eV. Then the work function $\varphi$ is determined as $\varphi = h\nu - E_{SEC}$, where $h\nu$ is the energy of employed radiation (here, 40.77 eV) and $E_{SEC}$ the measured binding energy of SEC. The measured spectra are given in Figure S10.

![Figure S10](image)

**Figure S10:** Work function measurement of CILs. (a) Overview of the valence band region measured with a 7 V sample bias (corrected to $E_F = 0$ eV). (b, c) The details of SEC (b) and $E_F$ (c) regions.
8. Change of work function during the thermal-induced transformation

Figure S11 shows temperature-induced deprotonation of 0.8 ML of BDA as a function of annealing temperature and simultaneously measured work function given as a function of the degree of deprotonation.

**Figure S11:** (a) Degree of deprotonation of carboxyl groups on the Ag(001) determined from the fitting of the O 1s peak measured by synchrotron radiation. The sample with 0.8 ML of BDA was gradually annealed up to 200 °C. After each annealing step, the heating was turned off, and the spectra were measured. The black line indicates the temperatures at which the degree of the
deprotonation only slightly changes with temperature; we associate this region with the $\beta_{(001)}$ phase. (b) The change of work function as a function of the degree of deprotonation. The work function was determined from the secondary electron cut-off measured after each annealing step together with the spectra that were used to determine the degree of deprotonation. The red horizontal line marks the measured substrate work function (4.36 eV). The two last points are given in grey as there is a loss of BDA molecules due to desorption.
9. Details of fitting of the XPS data: gradual deprotonation of the first layer

X-ray-induced deprotonation was followed in real-time by XPS on samples kept at 25 °C. The non-monochromatized Mg Kα X-ray source operating at 300 W power was positioned ~25 mm from the sample surface, which corresponds to ~8×10^{10} photons/s according to the manufacturer. The X-ray radiation slowly deprotonate the first BDA layer of: the \( \alpha(001) \) CIL slowly changes to \( \alpha(001) \) CIL. We have used the peak parameters obtained from pure phases as described above for the fitting given in Figure S12. We have assumed that the 2\textsuperscript{nd} layer BDA does not change during the irradiation. This is substantiated by (a) absence of deprotonation in the 2\textsuperscript{nd} layer on \( \delta(001) \) CIL even after annealing up to desorption of the 2\textsuperscript{nd} layer and (b) the fact that bonding of the carboxylate to the substrate makes deprotonation energetically favorable. Therefore, we have kept the intensity and gaussian widths of the 2\textsuperscript{nd} layer peaks constant during the fitting of the whole series. The positions, intensity ratios, and Gaussian widths of individual components were kept constant for both CIL phases. The only free fitting parameters were the intensities of the \( \alpha \) phase CIL peaks, the \( \alpha \) phase CIL peaks, and position of the 2\textsuperscript{nd} layer peaks. The degree of deprotonation was determined as the ratio of the carboxylate peak intensity to the total intensity of the 1\textsuperscript{st} layer (CIL) peaks.

Figure S13 shows the position of the 2\textsuperscript{nd} layer O 1s peak as a function of the degree of deprotonation of the BDA molecular layer. The density of interface dipoles given in Figure 4 of the main text is obtained by multiplying the degree of deprotonation by the density of BDA molecules (1.25 nm\(^{-2}\)) and the number of carboxyl groups per molecule (2 groups/molecule). The shift in energy levels is a relative shift from the initial 2\textsuperscript{nd} layer O 1s peak position 532.99 eV.

We should note that during synchrotron radiation measurements such damage was not observed because: the sample was irradiated for much shorter times (~30 minutes) with a comparable photon flux. To confirm minimal beam damage, we occasionally shifted the sample by few millimeters and compared the spectra from the fresh and long-illuminated spot; they looked identical in all cases.
Figure S12: Fitting of O 1s XPS spectra measured during 2500-min long X-ray exposure. The peaks associated with the $\alpha_{(001)}$ and $\tilde{\alpha}_{(001)}$ CIL (the 1st layer) and the 2nd layer are marked accordingly.
Figure S13: The shift of the 2nd layer O 1s peak as a function of the degree of deprotonation of the CIL. The variable degree of deprotonation was achieved during isostructural α(001) to α(001) transformation.
10. References


